

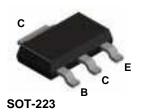
## MPSA65

## MMBTA65

## PZTA65







## **PNP Darlington Transistor**

This device is designed for applications requiring extremely high current gain at currents to 800 mA. Sourced from Process 61. See MPSA64 for characteristics.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CES</sub>	Collector-Emitter Voltage	30	V
V <sub>CBO</sub>	Collector-Base Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current - Continuous	1.2	А
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.

  2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units	
		MPSA65	*MMBTA65	**PZTA65	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

<sup>\*\*</sup>Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

# PNP Darlington Transistor (continued)

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TA = 25°C unless otherwise noted

Symbol	Parameter	Parameter Test Conditions		Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage	$I_C = 100 \ \mu A, I_B = 0$	30		V
І <sub>СВО</sub>	Collector-Cutoff Current	V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0		100	nA
I <sub>EBO</sub>	Emitter-Cutoff Current	$V_{EB} = 8.0 \text{ V}, I_{C} = 0$		100	nA
ON CHAR	RACTERISTICS*				
	RACTERISTICS*  DC Current Gain	Ic = 10 mA, V <sub>CE</sub> = 5.0 V	50,000		
h <sub>FE</sub>		I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 V I <sub>C</sub> = 100 mA, I <sub>B</sub> = 0.1 mA	50,000 20,000	1.5	V
	DC Current Gain	$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$	,	1.5 2.0	V
N <sub>FE</sub> V <sub>CE(sat)</sub> V <sub>BE(on)</sub>	DC Current Gain  Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$ $I_C = 100 \text{ mA}, I_B = 0.1 \text{ mA}$	,		•

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

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FACT Quiet Series TM PACMAN SuperSOT M-6
FAST ® POPTM SuperSOT M-8

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